PRELIMINARY

QUARTZ CRYSTAL OSCILLATOR

■ GENERAL DESCRIPTION

The NJU6392 series is a 3V operation C-MOS quartz crystal oscillator which consists of an oscillation amplifier and a 3-state output buffer.

This series is classed into four versions A, B, C and P according to their oscillation frequency range mentioned in the line-up table.

The oscillation amplifier incorporates feed-back resistance and oscillation capacitors(Cg, Cd), therefore, it requires no external component except quartz crystal.

Driverbility of the 3-state output buffer is 8mA (sink/source), thus it can drive C-MOS load.

■ PACKAGE OUTLINE

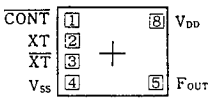
NJU6392XC

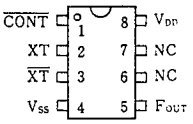
NJU6392XE

■ FEATURES

- Low Operating Voltage. -- 2.4~3.6V
- Maximum Oscillation Frequency (See Line-Up Table)
- Low Operating Current
- High Fan-out -- I_{OL}/I_{OH}=8mA
- 3-state Output Buffer
- Oscillation Capacitors Cg and Cd on-chip
- Oscillation Output Stand-by Function
- Package Outline -- CHIP / EMP 8
- C-MOS Technology

■ PAD LOCATION/PIN CONFIGURATION





■ LINE-UP TABLE

Type No.	Recommended Osc. Freq.	Output Freq.	Cg/Cd
NJU6392A	20~35MHz	fo	27pF
6392B	30~50MHz		19pF
6392C	45~75MHz		12/14pF
6392P	~75MHz		No

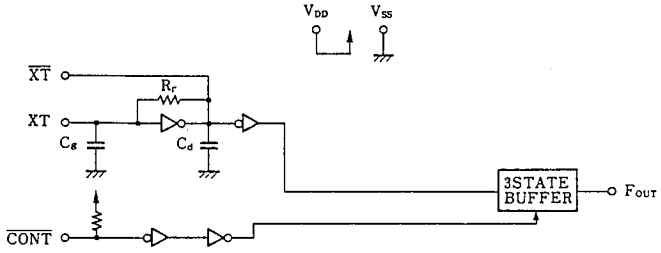
■ COORDINATES

Unit: μm

No.	PAD	X	Y
1	$\overline{CONT}$	-408	248
2	XT	-408	81
3	$\overline{XT}$	-408	- 86
4	V_{SS}	-408	-248
5	F_{OUT}	464	-248
8	V_{DD}	464	248

Chip Size : 1.29 X 0.8mm
Chip Center : X=0μm,Y=0μm
Chip Thickness : 400μm±30μm
(Note) No.6 and 7 terminals are only for package type information. There are no PAD on the chip.

■ BLOCK DIAGRAM



■ TERMINAL DESCRIPTION

NO.	SYMBOL	FUNCTION
1	$\overline{CONT}$	3-State Output Control $\overline{CONT}$: Output (F_{OUT}) H or OPEN : Output Frequency f_0 L : Output High Impedance
2	XT	Quartz Crystal Connecting Terminals
3	$\overline{XT}$	
4	V_{SS}	GND
5	F_{OUT}	Output frequency f_0
8	V_{DD}	+ 3 V

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■ ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{DD}	-0.5 ~ +7.0	V
Input Voltage	V_{IN}	V_{SS}-0.5 ~ V_{DD}+0.5	V
Output Voltage	V_O	-0.5 ~ V_{DD}+0.5	V
Input Current	I_{IN}	±10	mA
Output Current	I_O	±25	mA
Power Dissipation	P_D	200 (EMP)	mW
Operating Temperature Range	Topr	-40 ~ +85	℃
Storage Temperature Range	Tstg	-55 ~ +125	℃

(Note) Decoupling capacitor should be connected between V_{DD}-V_{SS} due to the stabilized operation for the circuit.

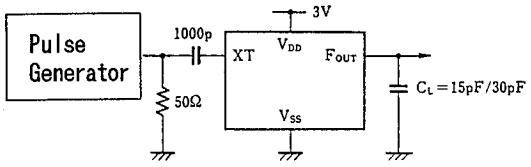
■ ELECTRICAL CHARACTERISTICS (Ta=25℃, V_{DD}=3V)

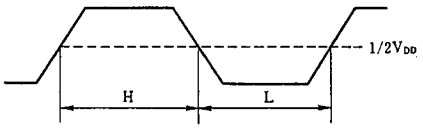
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage	V_{DD}		2.4		3.6	V
Operating Current	I_{DD1}	A Version fosc=24MHz,No Load		6	15	mA
	I_{DD2}	B Version fosc=48MHz,No Load		9	20	
	I_{DD3}	C Version fosc=48MHz,No Load (Note 1)		9	25	
Stand-by Current	Ist	$\overline{CONT}$,XT=V_{SS}, No Load(Note 2)			1	μA
Input Voltage	V_{IH}		2.4		3.0	V
	V_{IL}		0		0.6	
Output Current	I_{OH}	V_{OH}=2.7V	8			mA
	I_{OL}	V_{OL}=0.3V	8			
Input Current	I_{IN}	$\overline{CONT}$ Terminal, $\overline{CONT}$=V_{SS}	75	150	300	μA
3-St Off-leakage Current	I_{OZ}	$\overline{CONT}$=V_{SS}, F_{OUT}=V_{SS} or V_{DD}			±0.1	μA
Internal Capacitor (Note 3)	Cg/Cd	A Version fosc=24MHz,No Load		27		pF
		B Version fosc=48MHz,No Load		19		
		C Version fosc=48MHz,No Load		12/14		
Max. Oscillation Freq.	f_{MAX}	A Version	35			MHz
		B Version	50			
		C/P Version (Note 1)	75			
Output Signal Symmetry	SYM	C_L=15pF at 1.5V	45	50	55	%
		C_L=30pF at 1.5V				
Output Signal Rise Time	t_{r1}	C_L=15pF,10~90%		2	4	ns
	t_{r2}	C_L=30pF,10~90%			6	
Output Signal Fall Time	t_{f1}	C_L=15pF,90~10%		2	4	ns
	t_{f2}	C_L=30pF,90~10%			6	

(Note 1) Only P Version is measured with external capacitors contained 3pF for Cg and 3pF for Cd.
(Note 2) Excluding input current on $\overline{CONT}$ terminal.
(Note 3) P Version is not mentioned due to internal oscillation capacitors Cg and Cd separated.

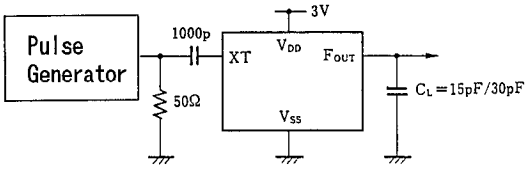
■ MEASUREMENT CIRCUITS

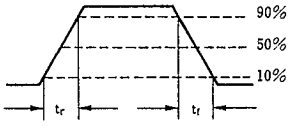
(1) Output Signal Symmetry





(2) Output Signal Rise / Fall Time





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